# **Dual 2-Input Exclusive-OR Gate**

The NL27WZ86 is a high performance dual 2-input Exclusive-OR Gate operating from a 1.65 V to 5.5 V supply.

#### **Features**

- Extremely High Speed:  $t_{PD}$  2.4 ns (typical) at  $V_{CC} = 5.0 \text{ V}$
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTL Compatible Interface Capability With 5.0 V TTL Logic with  $V_{CC}$  = 3.0 V
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Replacement for NC7WZ86
- Pb-Free Package is Available

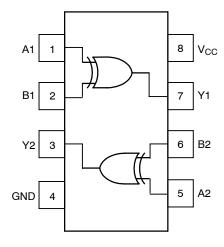


Figure 1. Pinout (Top View)

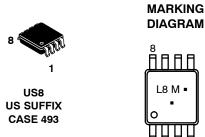
#### **PIN ASSIGNMENT**

Function
A1
B1
Y2
GND
A2
B2
Y1
V <sub>CC</sub>



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L8 = Device Code

M = Date Code\*

= Pb-Free Package(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

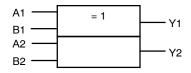


Figure 2. Logic Symbol

#### **FUNCTION TABLE**

Inp	Output Y = A + B	
Α	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

#### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	-0.5 to +7.0	V
Vo	DC Output Voltage	-0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current $V_l < GND$	-50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>O</sub> < GND	-50	mA
I <sub>O</sub>	DC Output Sink Current	±50	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	± 100	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
$T_J$	Junction Temperature under Bias	+ 150	°C
$\theta_{JA}$	Thermal Resistance (Note 1)	250	°C/W
$P_{D}$	Power Dissipation in Still Air at 85°C	250	mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage  Human Body Model (Note 2)  Machine Model (Note 3)  Charged Device Model (Note 4)	> 2000 > 200 N/A	V

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum–rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

- Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace with no air flow.
   Tested to EIA/JESD22-A114-A.
- 3. Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	٧
VI	Input Voltage	(Note 5)	0	5.5	V
V <sub>O</sub>	Output Voltage	(HIGH or LOW State)	0	5.5	V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+ 125	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$\begin{array}{c} V_{CC} = 1.8 \ V \pm 0.15 \ V \\ V_{CC} = 2.5 \ V \pm 0.2 \ V \\ V_{CC} = 3.0 \ V \pm 0.3 \ V \\ V_{CC} = 5.0 \ V \pm 0.5 \ V \end{array}$	0 0 0	20 20 10 5	ns/V

<sup>5.</sup> Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

#### DC ELECTRICAL CHARACTERISTICS

		V <sub>cc</sub>	T,	<sub>Δ</sub> = 25°	C	$-40^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 85^{\circ}\text{C}$			
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Unit	Condition
V <sub>IH</sub>	High-Level Input Voltage	1.65 to 1.95 2.3 to 5.5	0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		٧	
V <sub>IL</sub>	Low-Level Input Voltage	1.65 to 1.95 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	٧	
V <sub>OH</sub>	High-Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub>	1.65 1.8 2.3 3.0 4.5	1.55 1.7 2.2 2.9 4.4	1.65 1.8 2.3 3.0 4.5		1.55 1.7 2.2 2.9 4.4		V	Ι <sub>ΟΗ</sub> = -100 μΑ
		1.65 2.3 3.0 3.0 4.5	1.29 1.9 2.4 2.3 3.8	1.52 2.15 2.80 2.68 4.20		1.29 1.9 2.4 2.3 3.8		V	$\begin{split} I_{OH} &= -4 \text{ mA} \\ I_{OH} &= -8 \text{ mA} \\ I_{OH} &= -16 \text{ mA} \\ I_{OH} &= -24 \text{ mA} \\ I_{OH} &= -32 \text{ mA} \end{split}$
V <sub>OL</sub>	Low-Level Output Voltage V <sub>IN</sub> = V <sub>IL</sub>	1.65 1.8 2.3 3.0 4.5		0.0 0.0 0.0 0.0 0.0	0.1 0.1 0.1 0.1 0.1		0.1 0.1 0.1 0.1 0.1	V	I <sub>OL</sub> = 100 μA
		1.65 2.3 3.0 3.0 4.5		0.08 0.10 0.15 0.22 0.22	0.24 0.30 0.40 0.55 0.55		0.24 0.30 0.40 0.55 0.55	V	I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 8 mA I <sub>OL</sub> = 16 mA I <sub>OL</sub> = 24 mA I <sub>OL</sub> = 32 mA
I <sub>IN</sub>	Input Leakage Current	0 to 5.5			±1.0		± 1.0	μΑ	$0 \text{ V} \leq \text{V}_{\text{IN}} \leq 5.5 \text{ V}$
l <sub>OFF</sub>	Power Off Leakage Current	0.0			1.0		10	μА	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V
I <sub>CC</sub>	Quiescent Supply Current	1.65 to 5.5			1.0		10	μΑ	V <sub>IN</sub> = 5.5 V, GND

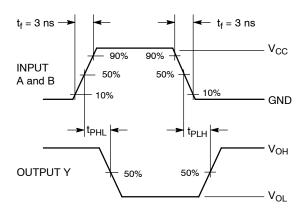
### AC ELECTRICAL CHARACTERISTICS $t_R$ = $t_F$ = 3.0 ns

			V <sub>CC</sub>	T <sub>A</sub> = 25°C		$-40^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 125^{\circ}\text{C}$			
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub>	Propagation Delay	$R_L = 1 \text{ M}\Omega$ , $C_L = 15 \text{ pF}$	1.8 ± 0.15	2.0	7.9	9.0	2.0	10.5	ns
t <sub>PHL</sub>	(Figure 3 and 4)	$R_L = 1 M\Omega$ , $C_L = 15 pF$	$2.5 \pm 0.2$	1.2	4.1	7.0	1.2	7.5	
		$R_L = 1 \text{ M}\Omega$ , $C_L = 15 \text{ pF}$	3.3 ± 0.3	0.8	3.0	4.8	0.8	5.2	
		$R_L = 500 \Omega, C_L = 50 pF$		1.2	3.8	5.4	1.2	5.9	
		$R_L = 1 \text{ M}\Omega$ , $C_L = 15 \text{ pF}$	5.0 ± 0.5	0.5	2.2	3.5	0.5	3.8	
		$R_L = 500 \Omega, C_L = 50 pF$		0.8	2.9	4.2	1.0	4.6	

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	2.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10 MHz, V <sub>CC</sub> = 3.3 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	9	pF
	(Note 6)	10 MHz, $V_{CC} = 5.5 \text{ V}$ , $V_{I} = 0 \text{ V}$ or $V_{CC}$	11	

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ . C<sub>PD</sub> is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .



A 1-MHz square input wave is recommended for propagation delay tests.

Figure 3. Switching Waveform

Figure 4. Test Circuit

#### **DEVICE ORDERING INFORMATION**

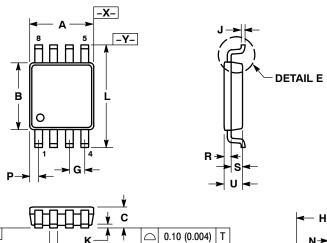
Device Order Number	Package Type	Tape and Reel Size <sup>†</sup>
NL27WZ86US	US8	178 mm, 3000 Units / Tape & Reel
NL27WZ86USG	US8 (Pb-Free)	178 mm, 3000 Units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

#### US8 **US SUFFIX** CASE 493-02

**ISSUE A** 



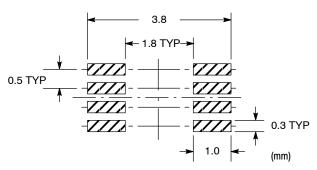
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH, PROTRUSION AND GATE BURD SUMMER SUM
- MOLD FLASH. PHO I HUSION AND GATE BURR SHALL NOT EXCEED 0.140 MM (0.0055") PER SIDE.

  4. DIMENSION "B" DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSION. INTER-LEAD FLASH AND PROTRUSION SHALL NOT E3XCEED 0.140 (0.0055") PER
- SHALL NOT E3XCEED 0.140 (0.0055") PE SIDE. 5. LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203 MM. (300-800"). 6. ALL TOLERANCE UNLESS OTHERWISE
- SPECIFIED  $\pm 0.0508$  (0.0002 ").

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.90	2.10	0.075	0.083
В	2.20	2.40	0.087	0.094
С	0.60	0.90	0.024	0.035
D	0.17	0.25	0.007	0.010
F	0.20	0.35	0.008	0.014
G	0.50	BSC	0.020	BSC
Н	0.40	REF	0.016	REF
J	0.10	0.18	0.004	0.007
K	0.00	0.10	0.000	0.004
L	3.00	3.20	0.118	0.126
М	0 °	6°	0 °	6 °
N	5 °	10 °	5°	10 °
Р	0.23	0.34	0.010	0.013
R	0.23	0.33	0.009	0.013
S	0.37	0.47	0.015	0.019
C	0.60	0.80	0.024	0.031
٧	0.12	BSC	0.005 BSC	

## -T-SEATING PLANE **R 0.10 TYP** 0.10 (0.004) M T Χ **DETAIL E**

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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